

## NCE P-Channel Enhancement Mode Power MOSFET

### Description

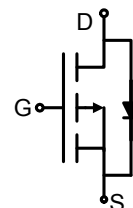
The NCE9435 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a load switch or in PWM applications.

### General Features

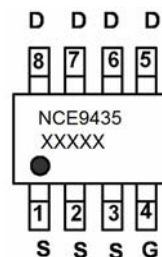
- $V_{DS} = -30V, I_D = -5.1A$   
 $R_{DS(ON)} < 90m\Omega @ V_{GS} = -4.5V$   
 $R_{DS(ON)} < 55m\Omega @ V_{GS} = -10V$
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

### Application

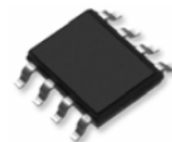
- PWM applications
- Load switch
- Power management



Schematic diagram



Marking and pin Assignment



SOP-8 top view

### Package Marking and Ordering Information

| Device Marking | Device  | Device Package | Reel Size | Tape width | Quantity   |
|----------------|---------|----------------|-----------|------------|------------|
| NCE9435        | NCE9435 | SOP-8          | Ø330mm    | 12mm       | 4000 units |

### Absolute Maximum Ratings ( $T_A = 25^\circ C$ unless otherwise noted)

| Parameter  | Symbol         | Limit      | Unit       |
|--|----------------|------------|------------|
| Drain-Source Voltage                             | $V_{DS}$       | -30        | V          |
| Gate-Source Voltage                              | $V_{GS}$       | $\pm 20$   | V          |
| Drain Current-Continuous                         | $I_D$          | -5.1       | A          |
| Drain Current-Pulsed <sup>(Note 1)</sup>         | $I_{DM}$       | -20        | A          |
| Maximum Power Dissipation                        | $P_D$          | 2.5        | W          |
| Operating Junction and Storage Temperature Range | $T_J, T_{STG}$ | -55 To 150 | $^\circ C$ |

### Thermal Characteristic

|   |                 |    |              |
|---|-----------------|----|--------------|
| Thermal Resistance, Junction-to-Ambient <sup>(Note 2)</sup> | $R_{\theta JA}$ | 50 | $^\circ C/W$ |
|---|-----------------|----|--------------|

### Electrical Characteristics ( $T_A = 25^\circ C$ unless otherwise noted)

| Parameter                      | Symbol     | Condition                      | Min | Typ | Max | Unit |
|--------------------------------|------------|--------------------------------|-----|-----|-----|------|
| <b>Off Characteristics</b>     |            |                                |     |     |     |      |
| Drain-Source Breakdown Voltage | $BV_{DSS}$ | $V_{GS} = 0V, I_D = -250\mu A$ | -30 | -33 | -   | V    |

|   |              |   |      |      |           |            |
|---|--------------|---|------|------|-----------|------------|
| Zero Gate Voltage Drain Current           | $I_{DSS}$    | $V_{DS}=-24V, V_{GS}=0V$                                  | -    | -    | -1        | $\mu A$    |
| Gate-Body Leakage Current                 | $I_{GSS}$    | $V_{GS}=\pm 20V, V_{DS}=0V$                               | -    | -    | $\pm 100$ | nA         |
| <b>On Characteristics</b> (Note 3)        |              |   |      |      |           |            |
| Gate Threshold Voltage                    | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=-250\mu A$                            | -1.1 | -1.6 | -2.1      | V          |
| Drain-Source On-State Resistance          | $R_{DS(ON)}$ | $V_{GS}=-10V, I_D=-5.1A$                                  | -    | 43   | 55        | m $\Omega$ |
|   |              | $V_{GS}=-4.5V, I_D=-4.2A$                                 | -    | 62   | 90        | m $\Omega$ |
| Forward Transconductance                  | $g_{FS}$     | $V_{DS}=-15V, I_D=-5.1A$                                  | 4    | 7    | -         | S          |
| <b>Dynamic Characteristics</b> (Note 4)   |              |   |      |      |           |            |
| Input Capacitance                         | $C_{iss}$    | $V_{DS}=-15V, V_{GS}=0V,$<br>$F=1.0MHz$                   | -    | 980  | -         | PF         |
| Output Capacitance                        | $C_{oss}$    |   | -    | 390  | -         | PF         |
| Reverse Transfer Capacitance              | $C_{rss}$    |   | -    | 135  | -         | PF         |
| <b>Switching Characteristics</b> (Note 4) |              |   |      |      |           |            |
| Turn-on Delay Time                        | $t_{d(on)}$  | $V_{DD}=-15V, I_D=-1A,$<br>$V_{GS}=-10V, R_{GEN}=6\Omega$ | -    | 14   | -         | nS         |
| Turn-on Rise Time                         | $t_r$        |   | -    | 12   | -         | nS         |
| Turn-Off Delay Time                       | $t_{d(off)}$ |   | -    | 56   | -         | nS         |
| Turn-Off Fall Time                        | $t_f$        |   | -    | 20   | -         | nS         |
| Total Gate Charge                         | $Q_g$        | $V_{DS}=-15V, I_D=-5.1A, V_{GS}=-10V$                     | -    | 11   | -         | nC         |
| Gate-Source Charge                        | $Q_{gs}$     |   | -    | 2.0  | -         | nC         |
| Gate-Drain Charge                         | $Q_{gd}$     |   | -    | 2.8  | -         | nC         |
| <b>Drain-Source Diode Characteristics</b> |              |   |      |      |           |            |
| Diode Forward Voltage (Note 3)            | $V_{SD}$     | $V_{GS}=0V, I_S=-5.1A$                                    | -    | -    | -1.2      | V          |

### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production

Typical Electrical and Thermal Characteristics



Figure 1: Switching Test Circuit



Figure 2: Switching Waveforms

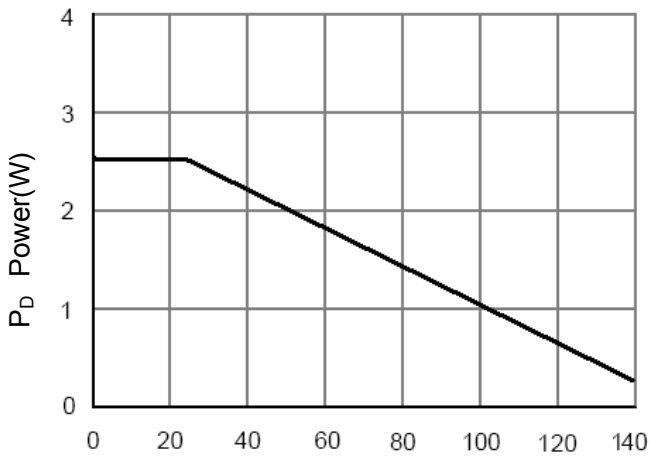


Figure 3 Power Dissipation

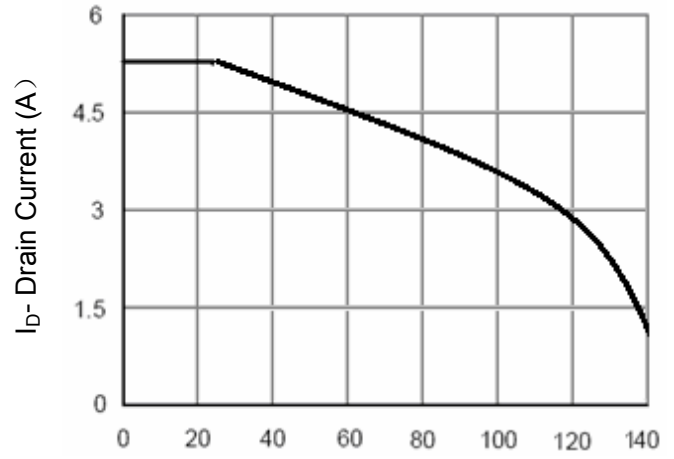


Figure 4 Drain Current

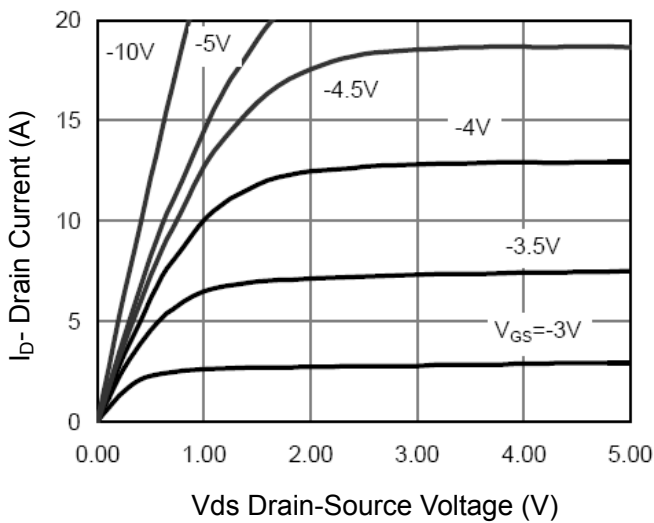


Figure 5 Output Characteristics

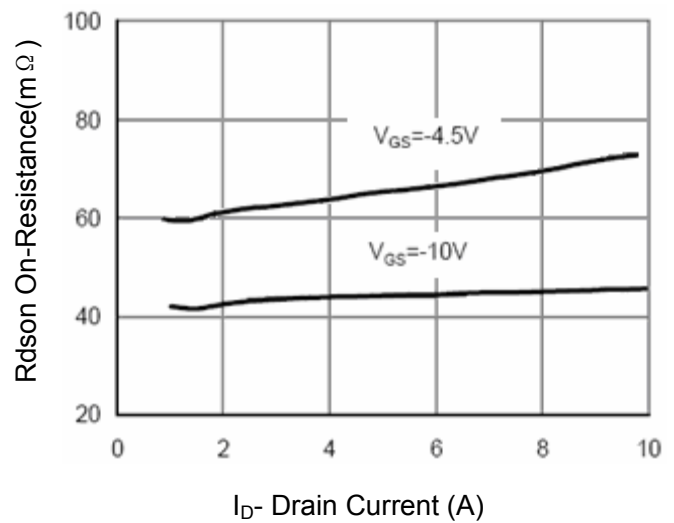


Figure 6 Drain-Source On-Resistance

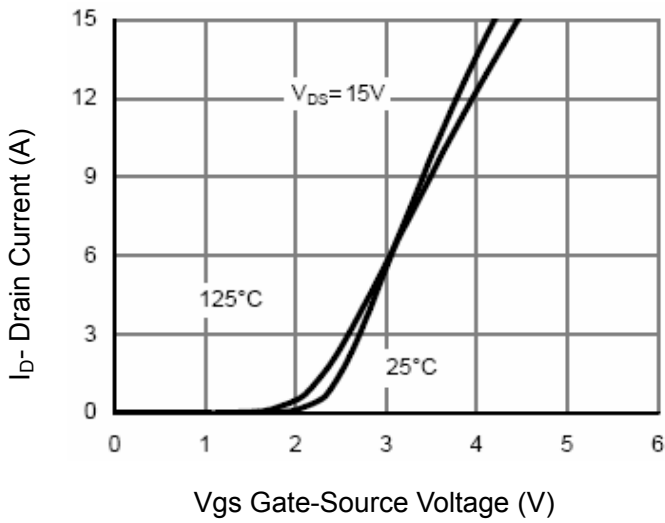


Figure 7 Transfer Characteristics

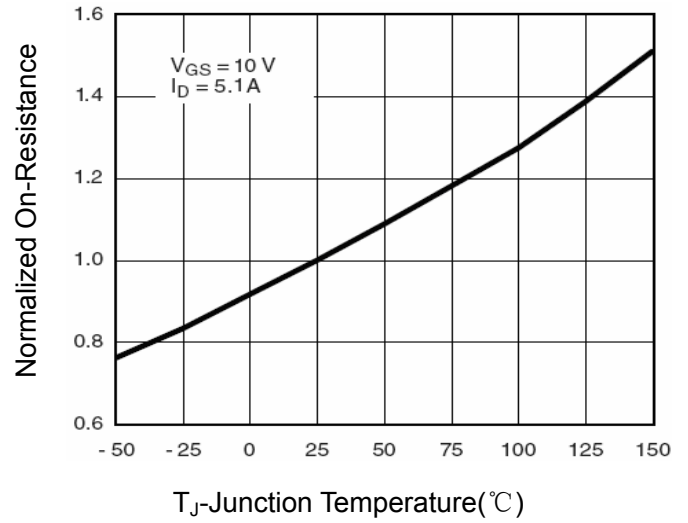


Figure 8 Drain-Source On-Resistance

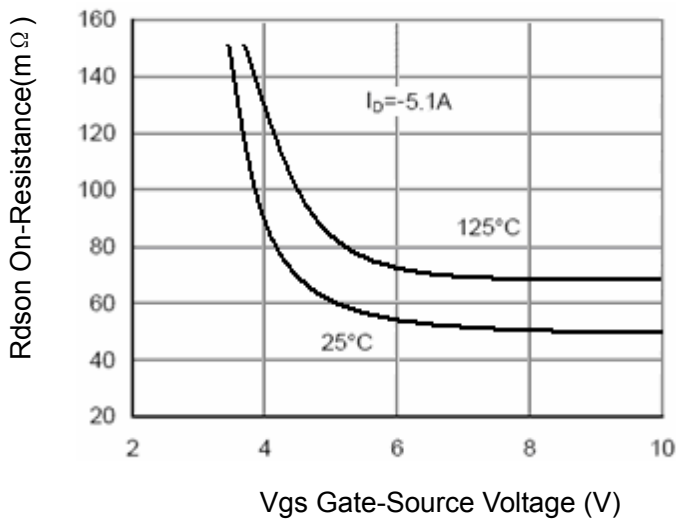


Figure 9 Rdson vs Vgs

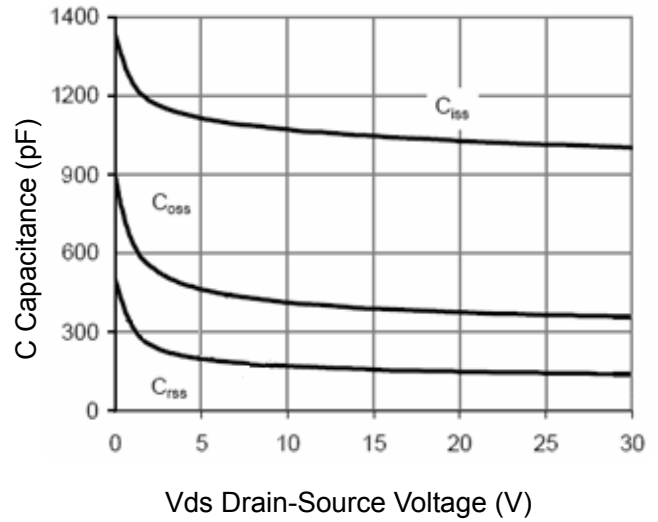


Figure 10 Capacitance vs Vds

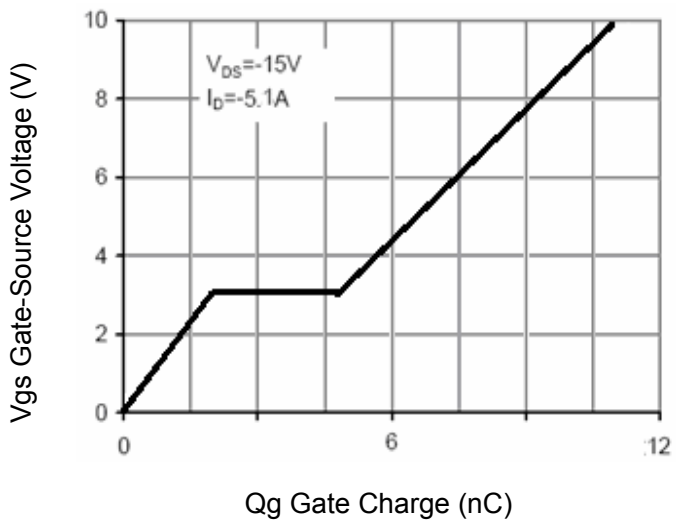


Figure 11 Gate Charge

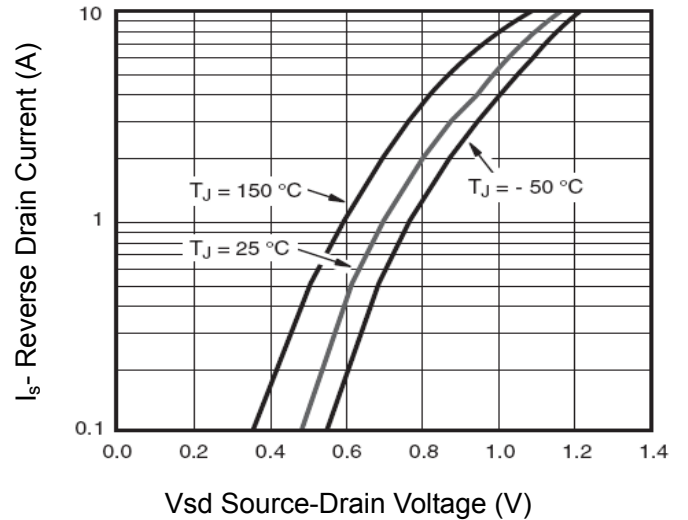


Figure 12 Source- Drain Diode Forward

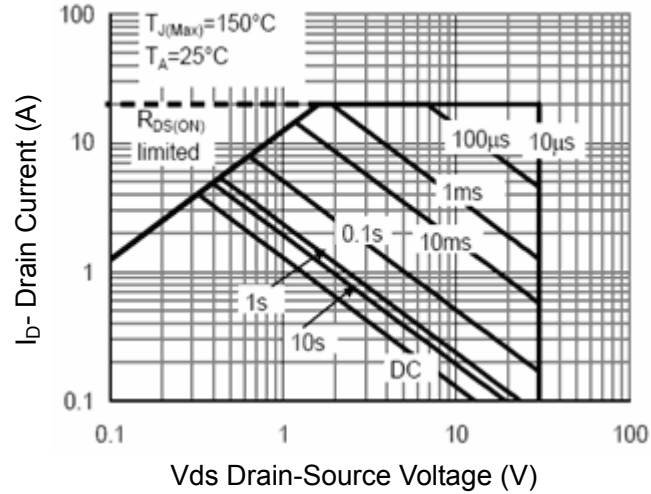


Figure 13 Safe Operation Area

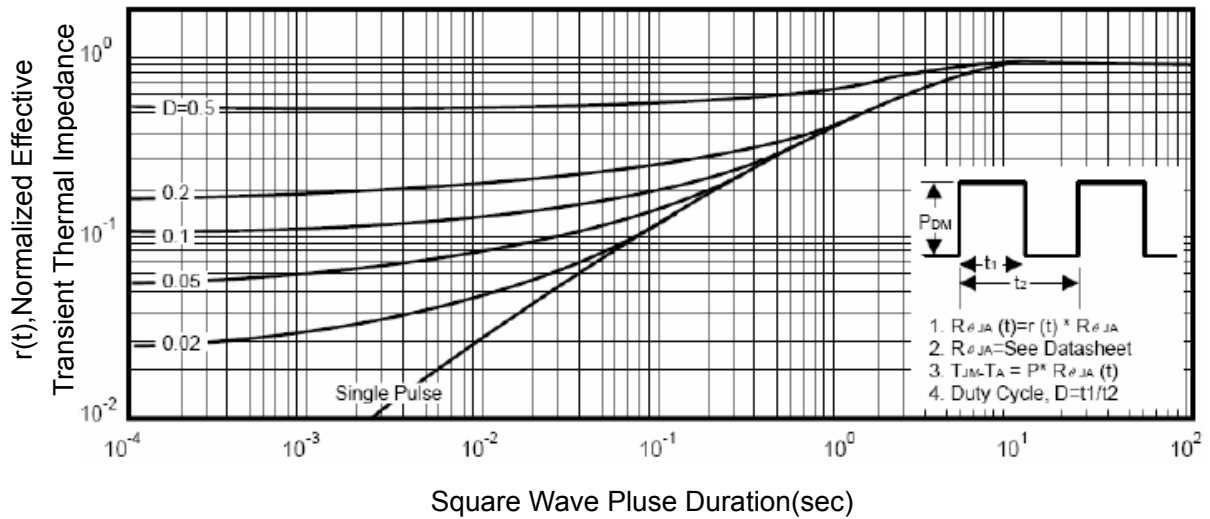


Figure 14 Normalized Maximum Transient Thermal Impedance

SOP-8 Package Information



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min.                      | Max.  | Min.                 | Max.  |
| A      | 1.350                     | 1.750 | 0.053                | 0.069 |
| A1     | 0.100                     | 0.250 | 0.004                | 0.010 |
| A2     | 1.350                     | 1.550 | 0.053                | 0.061 |
| b      | 0.330                     | 0.510 | 0.013                | 0.020 |
| c      | 0.170                     | 0.250 | 0.006                | 0.010 |
| D      | 4.700                     | 5.100 | 0.185                | 0.200 |
| E      | 3.800                     | 4.000 | 0.150                | 0.157 |
| E1     | 5.800                     | 6.200 | 0.228                | 0.244 |
| e      | 1.270(BSC)                |       | 0.050(BSC)           |       |
| L      | 0.400                     | 1.270 | 0.016                | 0.050 |
| θ      | 0°                        | 8°    | 0°                   | 8°    |

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